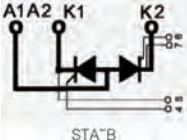
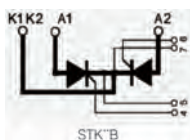
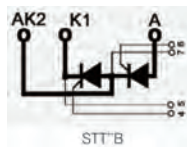


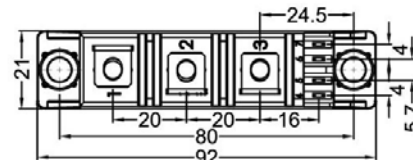
# STT90GKXXB

## Thyristor-Thyristor Modules



Type	$V_{RSM}$	$V_{RRM}$
	$V_{DSM}$	$V_{DRM}$
	V	V
<b>STT90GK08B</b>	900	800
<b>STT90GK12B</b>	1300	1200
<b>STT90GK14B</b>	1500	1400
<b>STT90GK16B</b>	1700	1600
<b>STT90GK18B</b>	1900	1800
<b>STT90GK20B</b>	2100	2000

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit
$I_{TRMS}, I_{FRMS}$ $I_{TAVM}, I_{FAVM}$	$T_V = T_{VJM}$ $T_C = 85^\circ C$ ; 180° sine	140 90	A
$I_{TSM}, I_{FSM}$	$T_V = 45^\circ C$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	1700 1800	A
	$T_V = T_{VJM}$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	1540 1640	
$\int i^2 dt$	$T_V = 45^\circ C$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	14450 13500	$A^2s$
	$T_V = T_{VJM}$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	11850 11300	
$(di/dt)_{cr}$	$T_V = T_{VJM}$ $f = 50Hz, t_p = 200\mu s$ $V_D = 2/3 V_{DRM}$ $I_G = 0.45A$ $di/dt = 0.45A/\mu s$ repetitive, $I_T = 250A$	150	A/ $\mu s$
	non repetitive, $I_T = I_{TAVM}$	500	
$(dv/dt)_{cr}$	$T_V = T_{VJM}$ ; $R_{GK} = \infty$ ; method 1 (linear voltage rise) $V_{DR} = 2/3 V_{DRM}$	1000	V/ $\mu s$
<b>P<sub>GM</sub></b>	$T_V = T_{VJM}$ $I_T = I_{TAVM}$ $t_p = 30\mu s$ $t_p = 300\mu s$	10	W
		5	
<b>P<sub>GAV</sub></b>		0.5	W
<b>V<sub>RGM</sub></b>		10	V
<b>T<sub>VJ</sub></b> <b>T<sub>VJM</sub></b> <b>T<sub>stg</sub></b>		-40...+125	$^\circ C$
		125	
		-40...+125	
<b>V<sub>ISOL</sub></b>	50/60Hz, RMS $I_{ISOL} \leq 1mA$ $t = 1min$ $t = 1s$	3000	V~
		3600	
<b>M<sub>d</sub></b>	Mounting torque (M5)	2.5-4.0/22-35	Nm/lb.in.
	Terminal connection torque (M5)	2.5-4.0/22-35	
<b>Weight</b>	Typical	110	g



# STT90GKXXB

## Thyristor-Thyristor Modules

Symbol	Test Conditions	Characteristic Values	Unit
<b>I<sub>RRM</sub>, I<sub>DRM</sub></b>	$T_{VJ}=T_{VJM}; V_R=V_{RRM}; V_D=V_{DRM}$	5	mA
<b>V<sub>TM</sub></b>	$I_{TM}=300A; T_{VJ}=25^{\circ}C$	1.74	V
<b>V<sub>TO</sub></b>	For power-loss calculations only ( $T_{VJ}=125^{\circ}C$ )	0.85	V
<b>r<sub>T</sub></b>		3.2	m $\Omega$
<b>V<sub>GT</sub></b>	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	2.5 2.6	V
<b>I<sub>GT</sub></b>	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	150 200	mA
<b>V<sub>GD</sub></b>	$T_{VJ}=T_{VJM}; V_D=2/3V_{DRM}$	0.2	V
<b>I<sub>GD</sub></b>		10	mA
<b>I<sub>L</sub></b>	$T_{VJ}=25^{\circ}C; t_p=10\mu s; V_D=6V$ $I_G=0.45A; di_G/dt=0.45A/\mu s$	450	mA
<b>I<sub>H</sub></b>	$T_{VJ}=25^{\circ}C; V_D=6V; R_{GK}=\infty$	200	mA
<b>t<sub>gd</sub></b>	$T_{VJ}=25^{\circ}C; V_D=1/2V_{DRM}$ $I_G=0.45A; di_G/dt=0.45A/\mu s$	2	us
<b>t<sub>q</sub></b>	$T_{VJ}=T_{VJM}; I_T=150A; t_p=200\mu s; -di/dt=10A/\mu s$ $V_R=100V; dv/dt=20V/\mu s; V_D=2/3V_{DRM}$ typ.	185	us
<b>Q<sub>s</sub></b>	$T_{VJ}=T_{VJM}; I_T, I_F=50A; -di/dt=6A/\mu s$	170	uC
<b>I<sub>RM</sub></b>		45	A
<b>R<sub>thJC</sub></b>	per thyristor/diode; DC current per module	0.3 0.15	K/W
<b>R<sub>thJK</sub></b>	per thyristor/diode; DC current per module	0.5 0.25	K/W
<b>ds</b>	Creeping distance on surface	12.7	mm
<b>dA</b>	Strike distance through air	9.6	mm
<b>a</b>	Maximum allowable acceleration	50	m/s <sup>2</sup>

### FEATURES

- \* International standard package
- \* Copper base plate
- \* Glass passivated chips
- \* Isolation voltage 3600 V~
- \* UL file NO.E310749
- \* RoHS compliant

### APPLICATIONS

- \* DC motor control
- \* Softstart AC motor controller
- \* Light, heat and temperature control

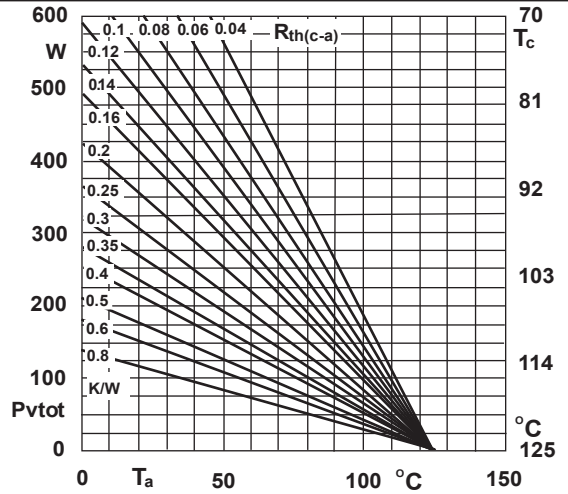
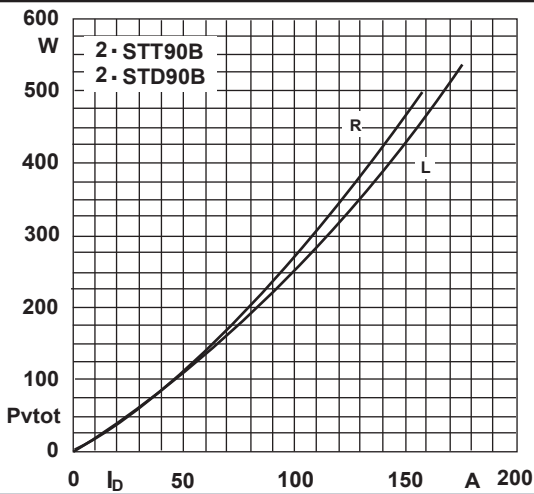
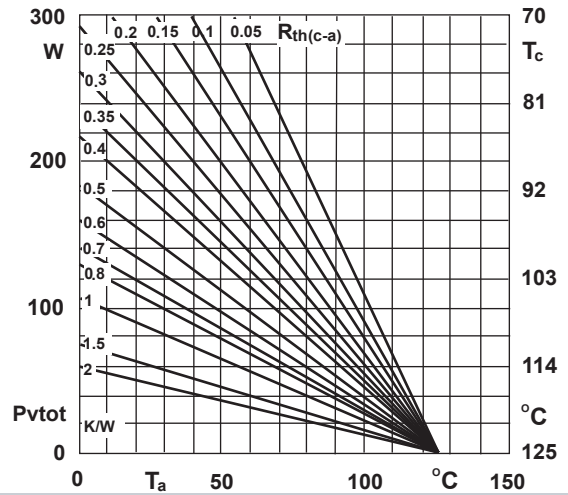
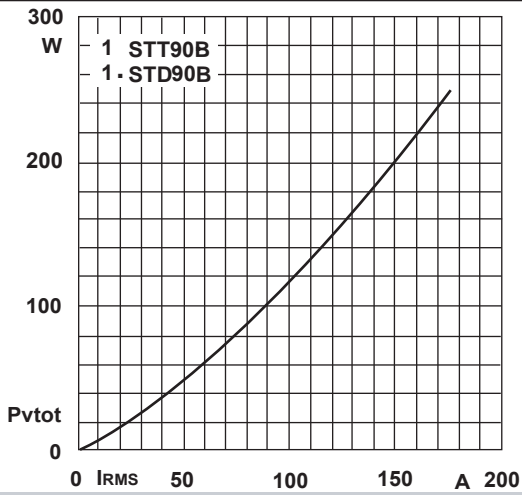
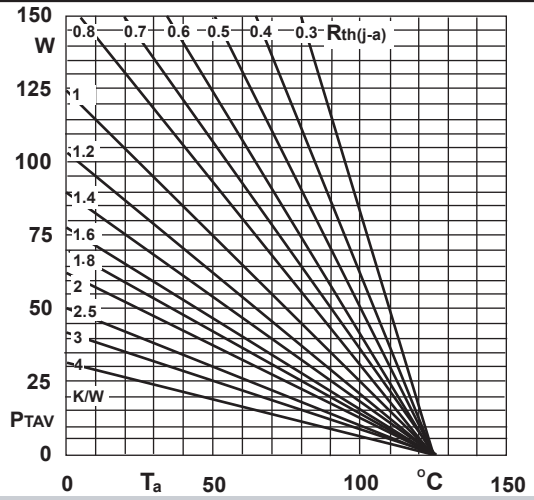
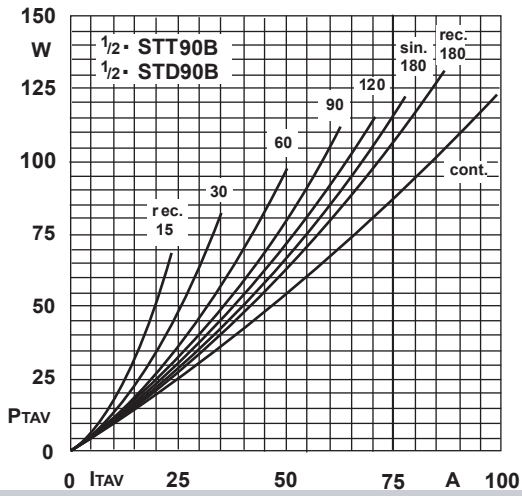
### ADVANTAGES

- \* Space and weight savings
- \* Simple mounting with two screws
- \* Improved temperature and power cycling
- \* Reduced protection circuits



# STT90GKXXB

## Thyristor-Thyristor Modules



# STT90GKXXB

## Thyristor-Thyristor Modules

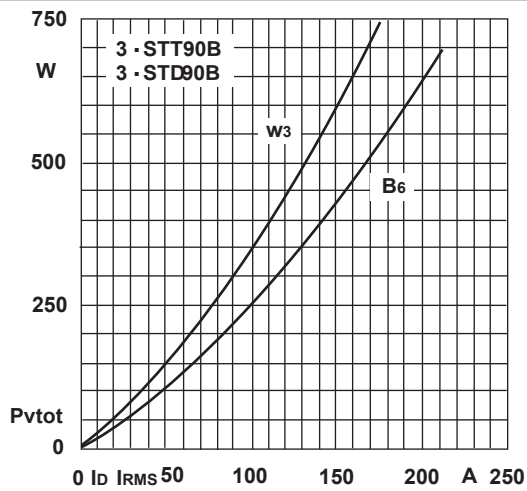


Fig.4L Power dissipation of three modules vs. direct and rms current

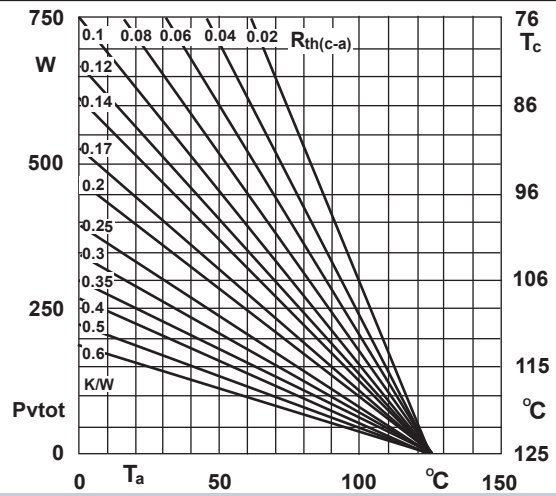


Fig.4R Power dissipation of three modules vs. case temp

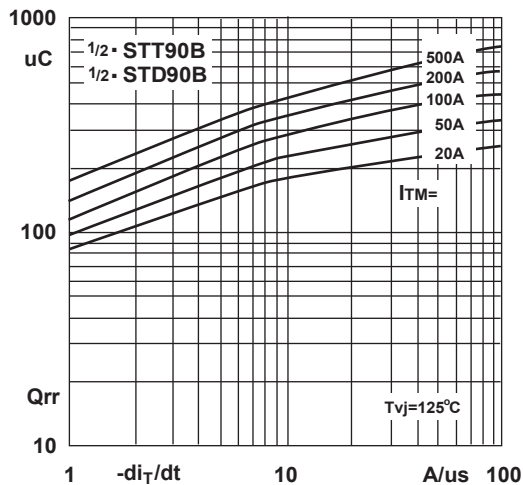


Fig.5 Recovered charge vs. current decrease

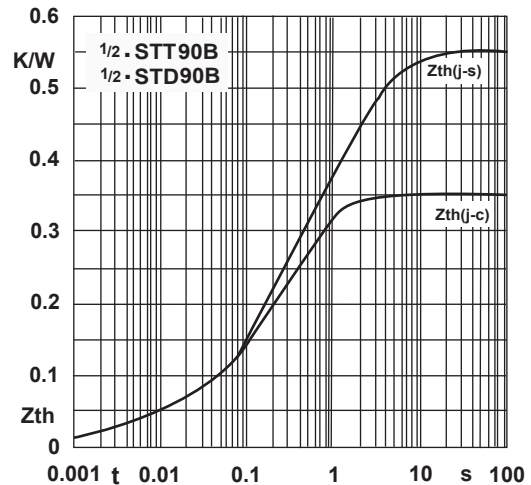


Fig.6 Transient thermal impedance vs. time

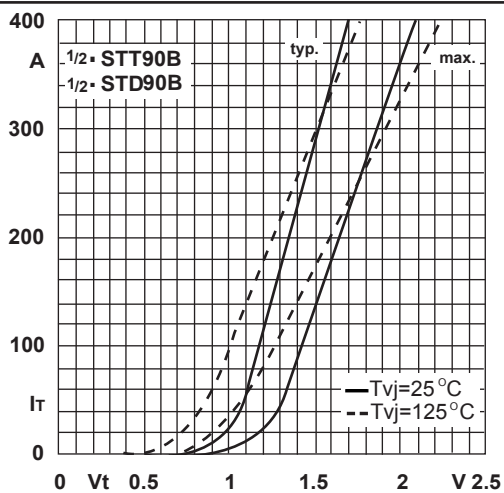


Fig.7 On-state characteristics

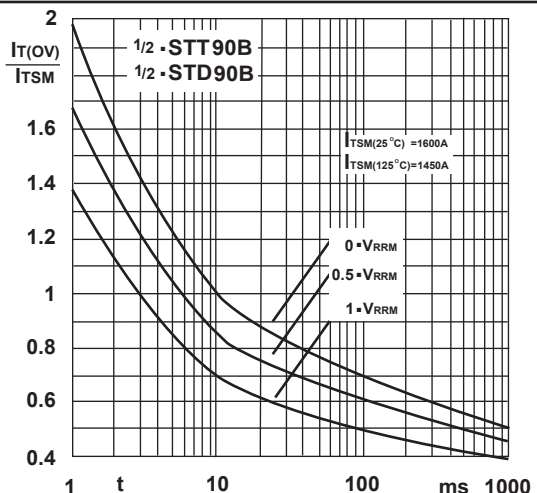


Fig.8 Surge overload current vs. time

